



# Research Spotlight Forum

SAND2019-6170PE

6.4.19 Quantum Information Sciences

## Overview of QIS Research at Sandia National Laboratories

PRESENTED BY:

Rick Muller, Manager, Quantum Initiatives

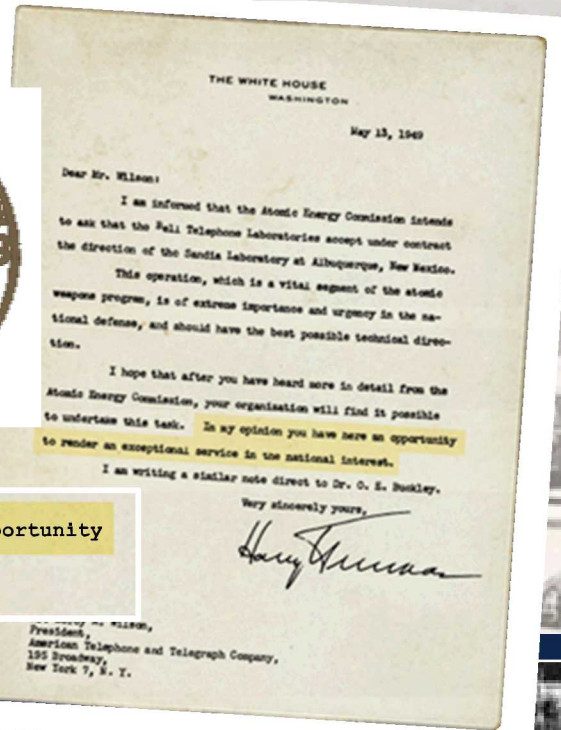
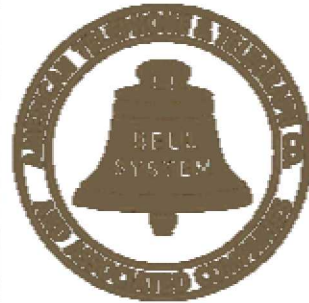
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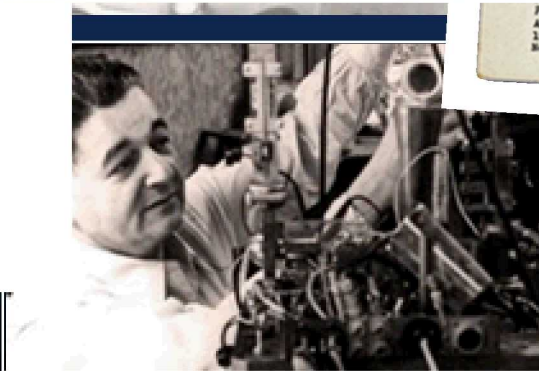


# Sandia's history

*Exceptional service in the national interest*



to undertake this task. In my opinion you have here an opportunity to render an exceptional service in the national interest.



- **July 1945:** Los Alamos creates Z Division
- Nonnuclear component engineering
- **November 1, 1949:** Sandia Laboratory established





# Quantum Information Sciences is Important at the National Level

## National Quantum Initiative

- QIS has important implications for US National and Economic Security
- The rest of the world is investing heavily in QIS: US cannot outspend the world.
- Create an all-of-government approach to coordinate US research in QIS

## Bill H.R. 6227

- Unified version of House and Senate Bills
- DOE (\$125M/yr), NIST (\$80M/yr), NSF (\$50M/yr) funding
- Signed by POTUS 12/21/2018
- Authorized but not Appropriated

## Opportunities:

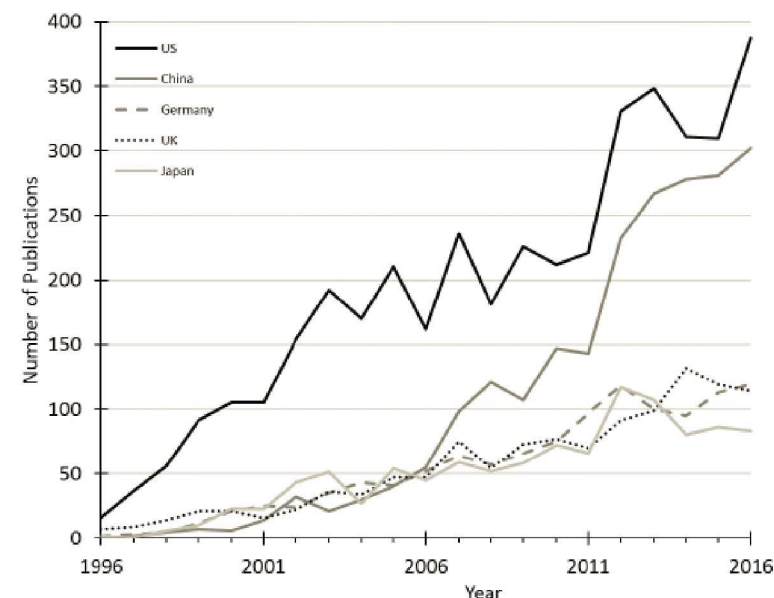
- NSF: Quantum Leap Challenge Institutes call open
- NIST: Quantum Economic Development Consortium (QED-C) underway
- DOE Quantum Centers RFI out, FOA expected 2020



Home » News » Press Releases

## House Approves the National Quantum Initiative Act

Sep 13, 2018 | Press Release



# Fabrication and Characterization Capabilities

- **MESA Fabs:** Trusted design, fabrication, packaging, testing – underpinning Quantum Info at Sandia
  - Silicon Fab: CMOS process, custom technologies (e.g. ion traps, Si quantum dots, Si photonics)
  - MicroFab: III-V compound semiconductor fab
  - *Wafer-level to die-level processing*
- **Center for Integrated Nanotechnologies (CINT):** *a DOE User Facility*
  - Integration Lab: Clean room with E-beam lithography, photolithography, deposition/etch, SEM/FIB
  - Characterization Lab: SEM/TEM, STM, Si qubit characterization/measurement, transport
- **Special Capabilities:**
  - Atomic Precision Fabrication (CINT): H-lithography for ultimate scale quantum dots and digital electronics
  - Si Photonics: devices thru CMOS integration, cryo SiP
  - Failure analysis: CMOS, superconducting electronics
  - Ion Beam Laboratory: nanoImplanter
- **Materials Science:** creation/synthesis, prototyping processes, measurements, characterization, modeling



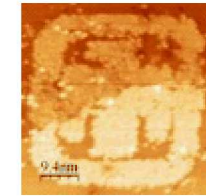
MESA



CINT



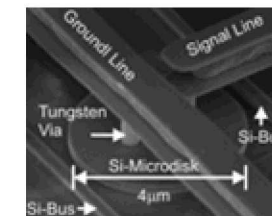
Atomic Precision Fab @ CINT



World-smallest Sandia "nanologo," at 0.7 nm precision.



World-first chip scale Si photonics quantum transceiver



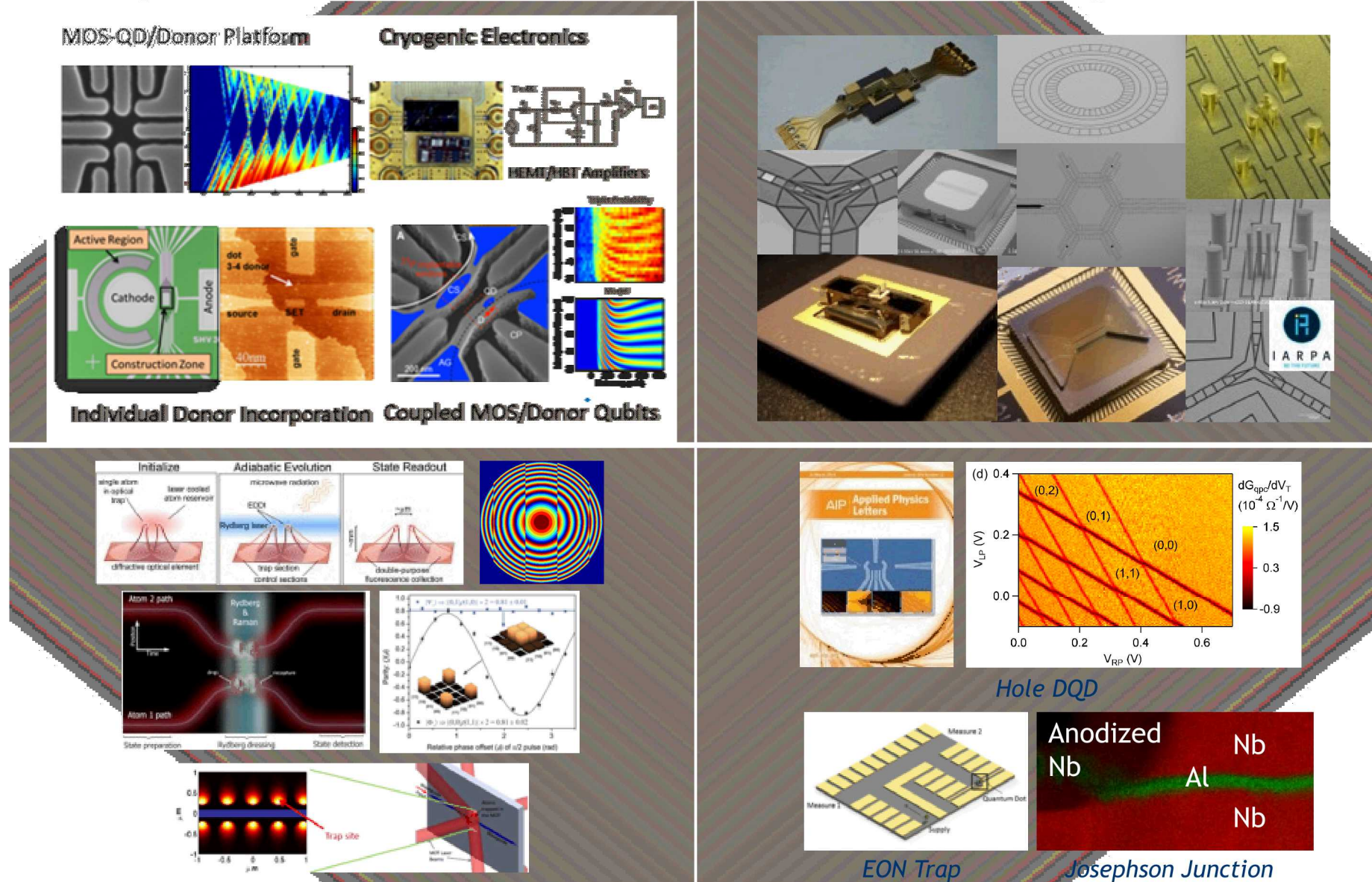
Si Photonics resonant optical modulator/filter

**Co-location with Si foundry:** industrial fab rigor, defect reduction (function and performance), semiconductor yield engineering - **QIS program accelerator**





# Sandia Expertise in Multiple Qubit Technologies



# Quantum Scientific Open User Testbed (QSCOUT)

PI: Peter Maunz

*DOE/ASCR facility to develop an open quantum testbed with 5-15 qubits realized in trapped-ion technology*

## Features:

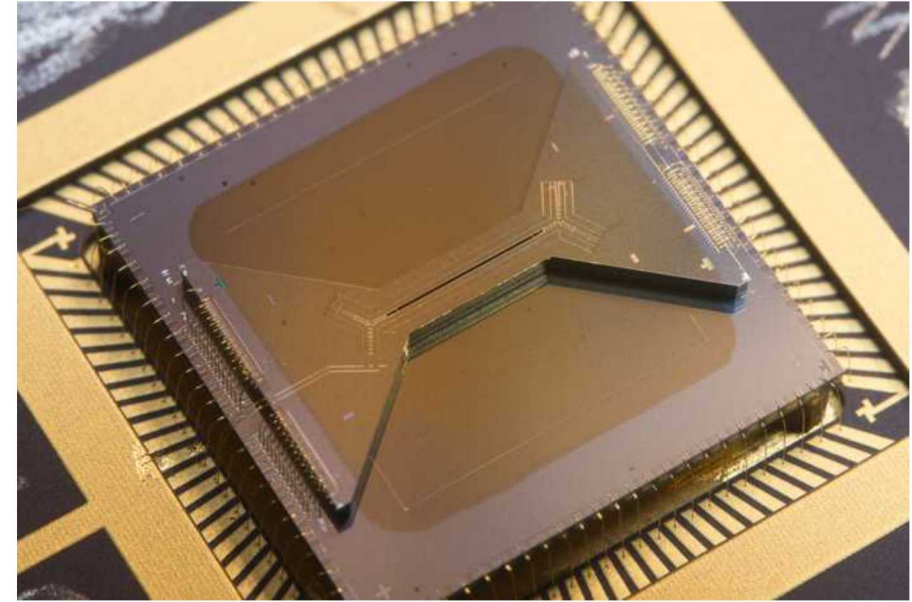
- Low single- and two-qubit error rates ( $<10^{-4}$ ,  $<2 \times 10^{-2}$ )
- All-to-all connectivity between qubits
- General algorithm execution capability
- Access to all relevant low-level implementation details
- Capability to change low-level gate implementation

## Availability:

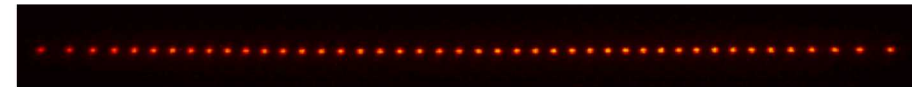
- Available to the DOE Scientific computing community
- First device will come online at end of 2019

## User support:

- Exemplar programs and demonstrations
- User workshops and conferences (together with LBNL)



Sandia's High Optical Access (HOA) ion trap



Chain of 44  $^{171}\text{Yb}^+$  ions trapped in the HOA trap



# Sandia Center for Integrated Quantum Sciences

The critical bottleneck to achieving quantum goals is **integration**. CIQS attacks this obstacle by addressing an array of critical S&T challenges:

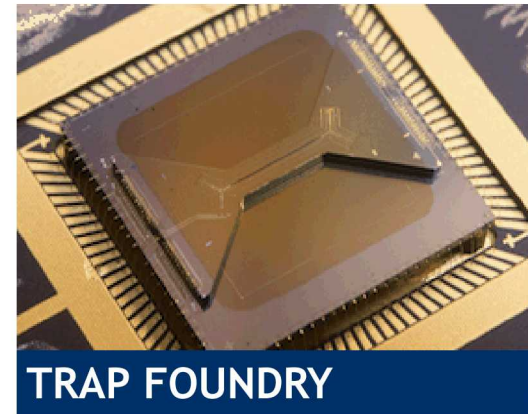
- How do we simultaneously increase qubit capacity and fidelity?
- Can we integrate multiple qubit technologies to reap the benefits of hybrid devices?
- What efficiencies can be achieved from vertical integration of control stacks?
- What system engineering optimizations can enable key applications?

## 5 Year Vision: **Integrating Ions and Photons for Science Impact**

- Build on the high fidelity and full connectivity available with trapped ions
- Enable improved devices making use of shuttling and photonics coupling
- Integrate chip-based photonic elements and electronics with existing physics devices.
- Develop algorithms and protocols to deal with connectivity limitations
- Extend to other AMO systems such as quantum sensing with trapped atoms
- ***Driven-by and impacting key science applications***

Beyond 5 years:

- Extend capabilities to heterogeneously integrate multiple complementary quantum technologies
- Develop and demonstrate an agile platform for chiplets representing different computing, communications, and sensing capabilities.



# 8 Postdocs Wanted!

Sandia has needs for postdocs in QIS:

- Low temperature measurement
- Semiconductor fabrication, measurement, and modeling
- AMO physics
- Modeling of experimental QIS systems
- Quantum algorithms and software

Email [quantum@sandia.gov](mailto:quantum@sandia.gov) for more information, or search for the current open postings at <http://www.sandia.gov>:

- 666828 Postdoctoral Appointee - Quantum Computing Theory (CA)
- 667638 Experimental Physicist - Quantum Information Science (early career)
- 667620 Quantum Information Science Postdoctoral Appointee
- 667561 Intern - Quantum Phenomena R&D Graduate Year Round

